









SN74LVC10A

SCAS284Q - JANUARY 1993 - REVISED AUGUST 2024

SN74LVC10A Triple 3-Input Positive-NAND Gate

1 Features

- Operates from 1.65V to 3.6V
- Specified from -40°C to 85°C and -40°C to 125°C
- Inputs accept voltages to 5.5V
- Max t_{pd} of 4.9ns at 3.3V
- Typical V_{OLP} (output ground bounce) < 0.8V at $V_{CC} = 3.3V$, $T_A = 25^{\circ}C$
- Typical V_{OHV} (output V_{OH} undershoot) $> 2V \text{ at } V_{CC} = 3.3V, T_A = 25^{\circ}C$
- Latch-up performance exceeds 250 mA per JESD
- ESD protection exceeds JESD 22
 - 2000V human-body model (A114-A)

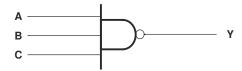
2 Description

This triple 3-input positive-NAND gate is designed for 1.65V to 3.6V V_{CC} operation.

Package Information

PART NUMBER	PACKAGE SIZE(1)	PACKAGE SIZE(2)	BODY SIZE(3)
	BQA (WQFN, 14)	3mm × 2.5mm	3mm × 2.5mm
	D (SOIC, 14)	8.65mm × 6mm	8.65mm × 3.9mm
SN74LVC10A	DB (SSOP, 14)	6.2mm × 7.8mm	6.2mm × 5.3mm
SIN/4LVC IUA	NS (SOP, 14)	10.2mm × 7.8mm	10.3mm × 5.3mm
	PW (TSSOP, 14)	5mm × 6.4mm	5mm × 4.4mm
	RGY (VQFN, 14)	3.5mm × 3.5mm	3.5mm × 3.5mm

- (1) For more information, see Section 10.
- The package size (length × width) is a nominal value and (2) includes pins, where applicable.
- The body size (length × width) is a nominal value and does not include pins.



Logic Diagram, Each Gate (Positive Logic)



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3 Pin Configuration and Functions

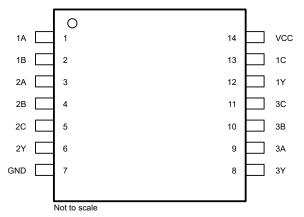


Figure 3-1. SN74LVC10A D, DB, NS, or PW Packages; 14-Pin SOIC, SSOP, SOP, or TSSOP (Top View)

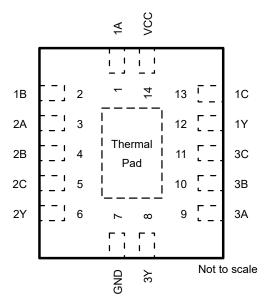


Figure 3-2. SN74LVC10A BQA Package, 14-Pin WQFN (Top View)

Table 3-1. Pin Functions

	PIN	I/O ⁽¹⁾	DECORPORTION
NAME	NO.	1/0(1)	DESCRIPTION
1A	1	Input	Channel 1, Input A
1B	2	Input	Channel 1, Input B
2A	3	Input	Channel 2, Input A
2B	4	Input	Channel 2, Input B
2C	5	Input	Channel 2, Input C
2Y	6	Output	Channel 2, Output Y
GND	7	_	Ground
3Y	8	Output	Channel 3, Output Y
3A	9	Input	Channel 3, Input A
3B	10	Input	Channel 3, Input B
3C	11	Input	Channel 3, Input C
1Y	12	Output	Channel 1, Output Y
1C	13	Input	Channel 1, Input C
V _{CC}	14	_	Positive Supply
Thermal pad		_	Connect the GND pin to the exposed thermal pad for correct operation. Connect the thermal pad to any internal PCB ground plane using multiple vias for good thermal performance.

(1) I = input, O = output, P = power, FB = feedback, GND = ground, N/A = not applicable



4 Specifications

4.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range	-0.5	6.5	V	
VI	Input voltage range ⁽¹⁾		-0.5	6.5	V
Vo	Output voltage range ⁽¹⁾ (2)		-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current			±50	mA
	Continuous current through V _{CC} or GND			±100	mA
T _{stg}	Storage temperature range		-65	150	°C
P _{tot}	Power dissipation	$T_A = -40^{\circ}C \text{ to } 125^{\circ}C^{(3)}$ (4)		500	mW

- (1) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
- (2) The value of V_{CC} is provided in the recommended operating conditions table.
- (3) For the D package: above 70°C, the value of P_{tot} derates linearly with 8 mW/K.
- (4) For the DB, NS, and PW packages: above 60°C, the value of P_{tot} derates linearly with 5.5 mW/K.

4.2 ESD Ratings

			VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

4.3 Recommended Operating Conditions

			T _A = 2	25°C	-40 TC) 85°C	-40 TO	125°C	UNIT	
			MIN	MAX	MIN	MAX	MIN	MAX	UNIT	
V	Cupply voltage	Operating	1.65	3.6	1.65	3.6	1.65	3.6	V	
V _{CC}	Supply voltage	Data retention only	1.5		1.5		1.5		v	
		V _{CC} = 1.65V to 1.95V	0.65 × V _{CC}		0.65 × V _{CC}		0.65 × V _{CC}			
V _{IH}	High-level input voltage	V _{CC} = 2.3V to 2.7V	1.7		1.7		1.7		V	
	voltage	V _{CC} = 2.7V to 3.6V	2		2		2			
		V _{CC} = 1.65V to 1.95V		0.35 × V _{CC}		0.35 × V _{CC}		0.35 × V _{CC}		
V _{IL}	, Low-level input voltage	V _{CC} = 2.3V to 2.7V		0.7		0.7		0.7	V	
		V _{CC} = 2.7V to 3.6V		0.8		0.8		0.8		
VI	Input voltage		0	5.5	0	5.5	0	5.5	V	
Vo	Output voltage		0	V _{CC}	0	V _{CC}	0	V _{CC}	V	
		V _{CC} = 1.65V		-4		-4		-4		
1	High-level	V _{CC} = 2.3V		-8		-8		-8	mA	
I _{OH}	output current	V _{CC} = 2.7V		-12		-12		-12	IIIA	
		V _{CC} = 3V		-24		-24		-24		
		V _{CC} = 1.65V		4		4		4		
	Low-level output	V _{CC} = 2.3V		8		8		8	m A	
I _{OL}	current	V _{CC} = 2.7V		12		12		12	mA	
		V _{CC} = 3V		24		24		24		

Product Folder Links: SN74LVC10A



4.4 Thermal Information

			SN74LVC10A					
	THERMAL METRIC ⁽¹⁾	BQA (WQFN) D (SOIC)		DB (SSOP) NS (SOP)		PW (TSSOP)	RGY (VQFN)	UNIT
		14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	102.3	127.8	96	123.8	150.8	92.1	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

4.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST CONDITIONS	V	T _A	= 25°C		-40 TO 8	5°C	-40 TO 125°C		UNIT
PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII
	I _{OH} = -100μA	1.65V to 3.6V	V _{CC} – 0.2			V _{CC} - 0.2		V _{CC} - 0.3		
	I _{OH} = -4mA	1.65V	1.29			1.2		1.05		
V _{OH}	I _{OH} = –8mA	2.3 V	1.9			1.7		1.55		V
	I _{OH} = -12mA	2.7V	2.2			2.2		2.05		
	IOH IZIIIA	3V	2.4			2.4		2.25		
	I _{OH} = -24mA	3V	2.3			2.2		2		
	I _{OL} = 100μA	1.65V to 3.6V			0.1		0.2		0.3	
	I _{OL} = 4mA	1.65V			0.24		0.45		0.6	
V _{OL}	I _{OL} = 8mA	2.3V	,		0.3		0.7		0.75	V
	I _{OL} = 12mA	2.7V			0.4		0.4		0.6	
	I _{OL} = 24mA	3V			0.55		0.55		0.8	
I _I	V _I = 5.5V or GND	3.6V			±1		±5		±20	μΑ
Icc	$V_1 = V_{CC}$ or $I_0 = 0$	3.6V			1		10		40	μΑ
ΔI _{CC}	One input at V _{CC} – 0.6 V, Other inputs at V _{CC} or GND	2.7V to 3.6V			500		500		5000	μΑ
Ci	V _I = V _{CC} or GND	3.3V		5						pF

4.6 Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM	то	V	T	= 25°C		-40 TO	85°C	-40 TO	125°C	UNIT
PARAMETER	(INPUT)	(OUTPUT)	V _{cc}	MIN	TYP	MAX	MIN	MAX	MIN	MAX	ONIT
			1.8V ± 0.15V	1	4.2	10.1	1	10.6	1	12.1	
	A, B, or C	_	2.5V ± 0.2V	1	2.9	7.3	1	7.8	1	9.9	no
^L pd	А, В, ОГС	,	2.7V	1	3.1	5.6	1	5.8	1	7.4	ns
			3.3V ± 0.3V	1	2.7	4.7	1	4.9	1	6	
t _{sk(o)}			3.3V ± 0.3V					1		1.5	ns

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4.7 Operating Characteristics

 $T_A = 25^{\circ}C$

	PARAMETER		V _{CC}	TYP	UNIT
			1.8V	9	
C _{pd}	Power dissipation capacitance per gate	f = 10 MHz	2.5V	10	pF
			3.3V	11	

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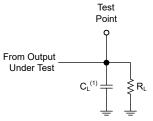
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5 Parameter Measurement Information

Phase relationships between waveforms were chosen arbitrarily for the examples listed in the following table. All input pulses are supplied by generators having the following characteristics: PRR \leq 1MHz, $Z_O = 50\Omega$, $t_t \leq$ 2.5ns.

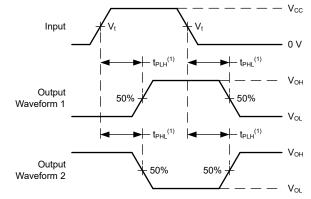
The outputs are measured individually with one input transition per measurement.

V _{cc}	V _t	R _L	CL	ΔV
1.8V ± 0.15V	V _{CC} /2	1kΩ	30pF	0.15V
2.5V ± 0.2V	V _{CC} /2	500Ω	30pF	0.15V
2.7V	1.5V	500Ω	50pF	0.3V
3.3V ± 0.3V	1.5V	500Ω	50pF	0.3V



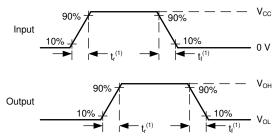
(1) C_L includes probe and test-fixture capacitance.

Figure 5-1. Load Circuit for Push-Pull Outputs



(1) The greater between t_{PLH} and t_{PHL} is the same as t_{pd} .

Figure 5-2. Voltage Waveforms Propagation Delays



(1) The greater between t_r and t_f is the same as t_t .

Figure 5-3. Voltage Waveforms, Input and Output Transition Times



6 Detailed Description

6.1 Overview

The SN74LVC10A performs the Boolean function $Y = \overline{A \cdot B \cdot C}$ or $Y = \overline{A} + \overline{B} + \overline{C}$ in positive logic.

Inputs can be driven from either 3.3V or 5V devices. This feature allows the use of these devices as translators in a mixed 3.3V/5V system environment.

6.2 Functional Block Diagram

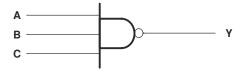


Figure 6-1. Logic Diagram, Each Gate (Positive Logic)

6.3 Device Functional Modes

Table 6-1. Function Table (Each Gate)

	INPUTS	OUTPUT	
Α	В	С	Y
Н	Н	Н	L
L	Χ	X	Н
X	L	X	Н
Х	Χ	L	Н

Product Folder Links: SN74LVC10A

7 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

7.1 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating in the *Recommended Operating Conditions*.

Each V_{CC} pin must have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1 μ F is recommended; if there are multiple V_{CC} pins, then 0.01 μ F or 0.022 μ F is recommended for each power pin. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. A 0.1 μ F and a 1 μ F are commonly used in parallel. The bypass capacitor must be installed as close to the power pin as possible for best results.

7.2 Layout

7.2.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices inputs must not ever be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or VCC, whichever makes more sense for the logic function or is more convenient.

7.2.2 Layout Example

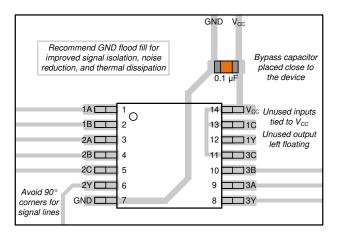


Figure 7-1. Example layout for the SN74LVC10A



8 Device and Documentation Support

8.1 Documentation Support (Analog)

8.1.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to order now.

Table 8-1. Related Links

PARTS	PRODUCT FOLDER	ORDER NOW	ORDER NOW TECHNICAL DOCUMENTS		SUPPORT & COMMUNITY	
SN74LVC10A	Click here	Click here	Click here	Click here	Click here	

8.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on Notifications to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.3 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

8.4 Trademarks

TI E2E[™] is a trademark of Texas Instruments.

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8.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications

8.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision P (May 2024) to Revision Q (August 2024)

Page

Updated R0JA values: D = 86 to 127.8, NS = 76 to 123.8, PW = 113 to 150.8, RGY = 47 to 92.1, all values in °C/W......5

Changes from Revision O (July 2005) to Revision P (May 2024)

Page

- Added BQA package to Package Information table, Pin Configuration and Functions section, and Thermal Information table......1
- Added Applications section, Package Information table, ESD Ratings table, Thermal Information table, Device Functional Modes, Application and Implementation section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section......1

Product Folder Links: SN74LVC10A



10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: SN74LVC10A

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
SN74LVC10ABQAR	Active	Production	WQFN (BQA) 14	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC10A
SN74LVC10ABQAR.A	Active	Production	WQFN (BQA) 14	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC10A
SN74LVC10AD	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC10A
SN74LVC10AD.B	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC10A
SN74LVC10ADBR	Active	Production	SSOP (DB) 14	2000 LARGE T&R	Yes	NIPDAU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC10A
SN74LVC10ADBR.A	Active	Production	SSOP (DB) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC10A
SN74LVC10ADBR.B	Active	Production	SSOP (DB) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC10A
SN74LVC10ADG4	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC10A
SN74LVC10ADR	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC10A
SN74LVC10ADR.A	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC10A
SN74LVC10ADR.B	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC10A
SN74LVC10ADT	Active	Production	SOIC (D) 14	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC10A
SN74LVC10ADT.B	Active	Production	SOIC (D) 14	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC10A
SN74LVC10ANSR	Active	Production	SOP (NS) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC10A
SN74LVC10ANSR.A	Active	Production	SOP (NS) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC10A
SN74LVC10ANSR.B	Active	Production	SOP (NS) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC10A
SN74LVC10APW	Active	Production	TSSOP (PW) 14	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC10A
SN74LVC10APW.B	Active	Production	TSSOP (PW) 14	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC10A
SN74LVC10APWR	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC10A
SN74LVC10APWR.A	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC10A
SN74LVC10APWR.B	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC10A
SN74LVC10APWRG4	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC10A
SN74LVC10APWRG4.A	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC10A
SN74LVC10APWRG4.B	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC10A
SN74LVC10APWT	Active	Production	TSSOP (PW) 14	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC10A
SN74LVC10APWT.B	Active	Production	TSSOP (PW) 14	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC10A
SN74LVC10ARGYR	Active	Production	VQFN (RGY) 14	3000 LARGE T&R	Yes	NIPDAU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	LC10A
SN74LVC10ARGYR.A	Active	Production	VQFN (RGY) 14	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	LC10A
SN74LVC10ARGYR.B	Active	Production	VQFN (RGY) 14	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	LC10A

PACKAGE OPTION ADDENDUM

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- (1) Status: For more details on status, see our product life cycle.
- (2) Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.
- (3) RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.
- (4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.
- (5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.
- (6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

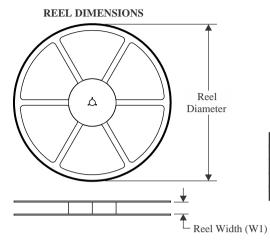
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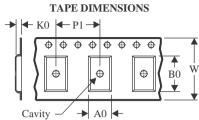
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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

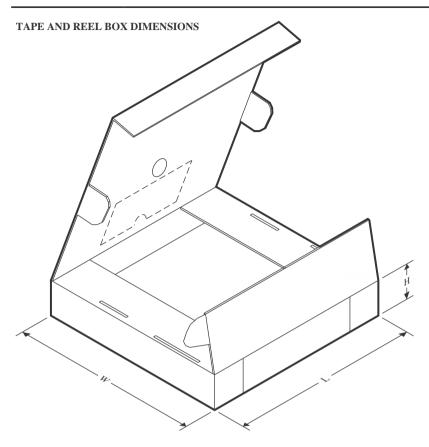


*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC10ABQAR	WQFN	BQA	14	3000	180.0	12.4	2.8	3.3	1.1	4.0	12.0	Q1
SN74LVC10ADBR	SSOP	DB	14	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
SN74LVC10ADR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LVC10ADT	SOIC	D	14	250	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LVC10ANSR	SOP	NS	14	2000	330.0	16.4	8.1	10.4	2.5	12.0	16.0	Q1
SN74LVC10APWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC10APWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC10APWT	TSSOP	PW	14	250	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC10ARGYR	VQFN	RGY	14	3000	330.0	12.4	3.75	3.75	1.15	8.0	12.0	Q1



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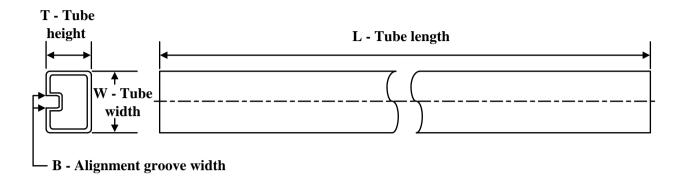
*All dimensions are nominal

7 ili dimensionis are nominal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC10ABQAR	WQFN	BQA	14	3000	210.0	185.0	35.0
SN74LVC10ADBR	SSOP	DB	14	2000	353.0	353.0	32.0
SN74LVC10ADR	SOIC	D	14	2500	353.0	353.0	32.0
SN74LVC10ADT	SOIC	D	14	250	213.0	191.0	35.0
SN74LVC10ANSR	SOP	NS	14	2000	353.0	353.0	32.0
SN74LVC10APWR	TSSOP	PW	14	2000	353.0	353.0	32.0
SN74LVC10APWRG4	TSSOP	PW	14	2000	353.0	353.0	32.0
SN74LVC10APWT	TSSOP	PW	14	250	353.0	353.0	32.0
SN74LVC10ARGYR	VQFN	RGY	14	3000	353.0	353.0	32.0

PACKAGE MATERIALS INFORMATION

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TUBE



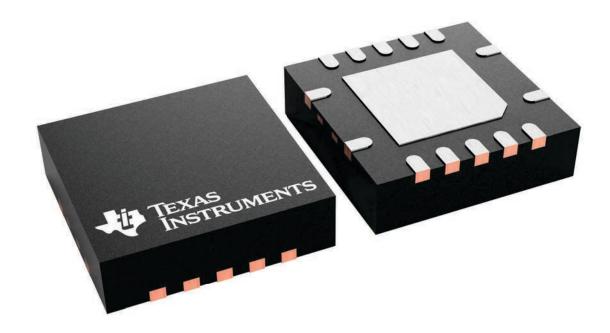
*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN74LVC10AD	D	SOIC	14	50	506.6	8	3940	4.32
SN74LVC10AD.B	D	SOIC	14	50	506.6	8	3940	4.32
SN74LVC10ADG4	D	SOIC	14	50	506.6	8	3940	4.32
SN74LVC10APW	PW	TSSOP	14	90	530	10.2	3600	3.5
SN74LVC10APW.B	PW	TSSOP	14	90	530	10.2	3600	3.5

3.5 x 3.5, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

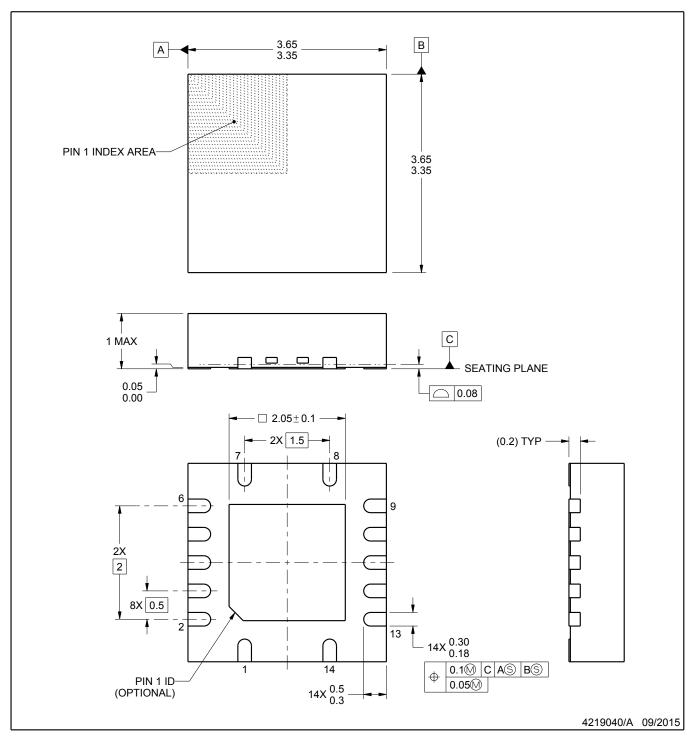
This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



INSTRUMENTS www.ti.com



PLASTIC QUAD FLATPACK - NO LEAD

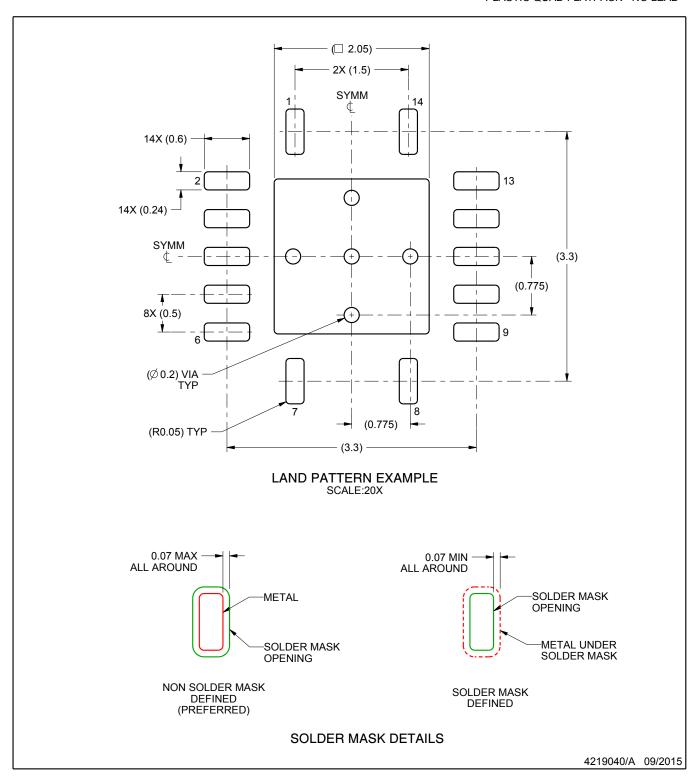


NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- This drawing is subject to change without notice.
 The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC QUAD FLATPACK - NO LEAD

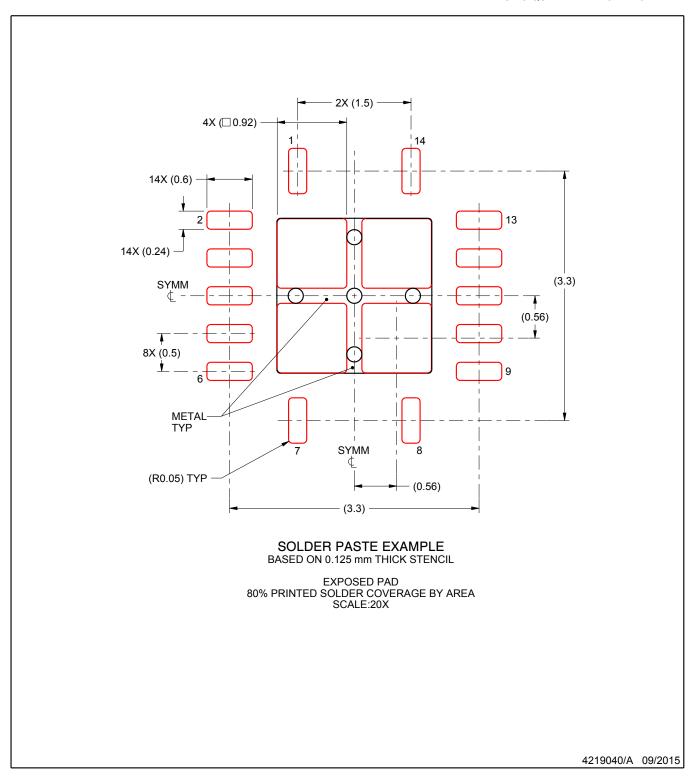


NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.





SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
- 5. Reference JEDEC registration MS-012, variation AB.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

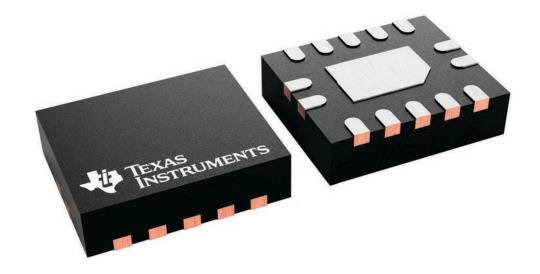
- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



2.5 x 3, 0.5 mm pitch

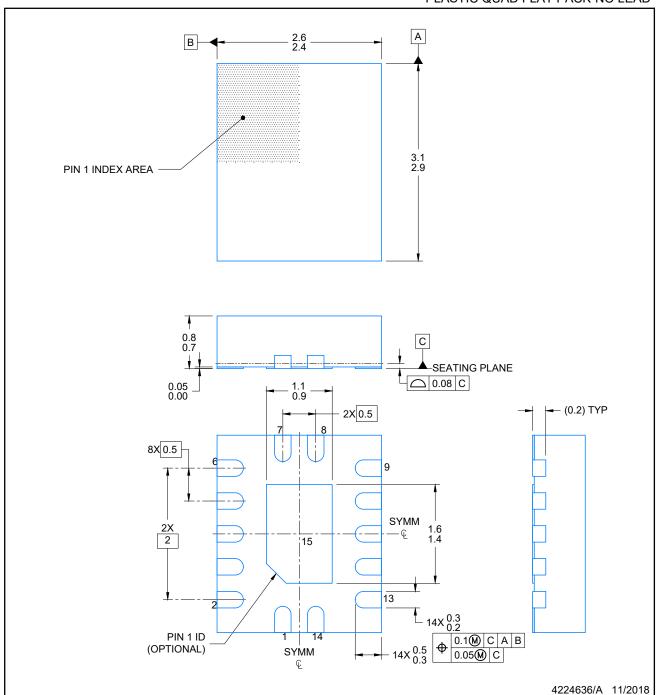
PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



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PLASTIC QUAD FLAT PACK-NO LEAD

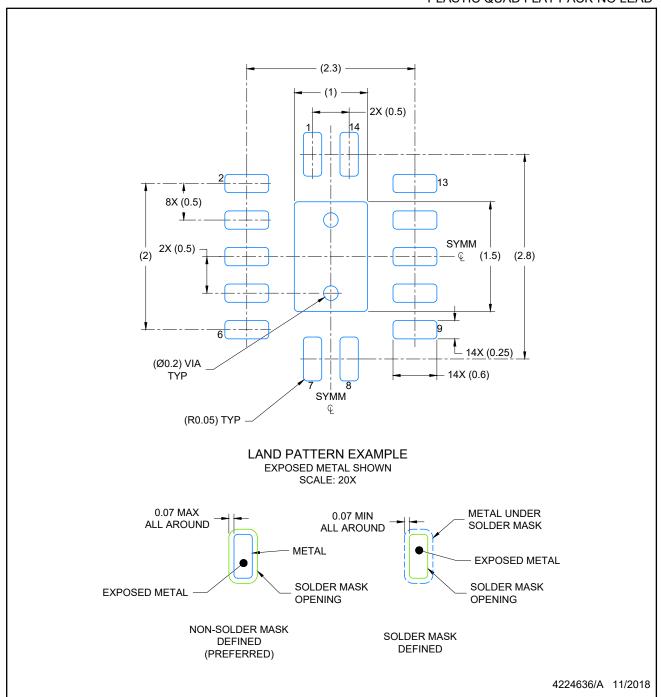


NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.



PLASTIC QUAD FLAT PACK-NO LEAD

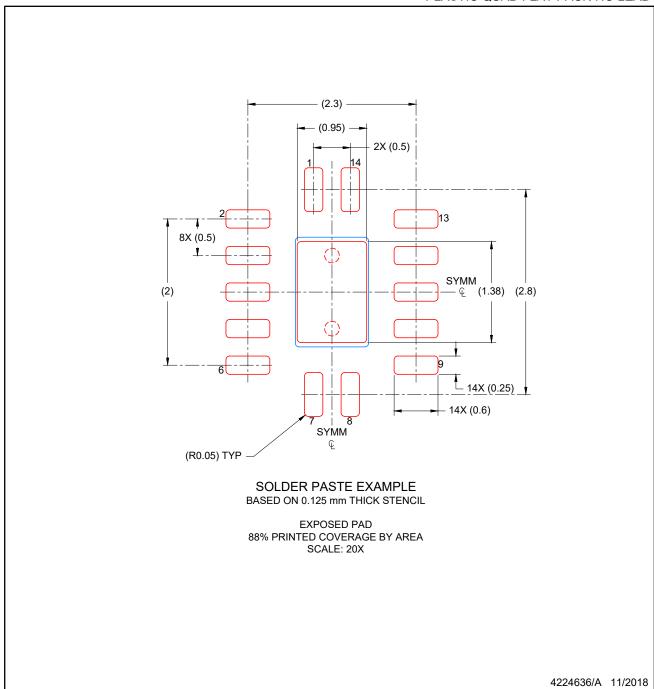


NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC QUAD FLAT PACK-NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

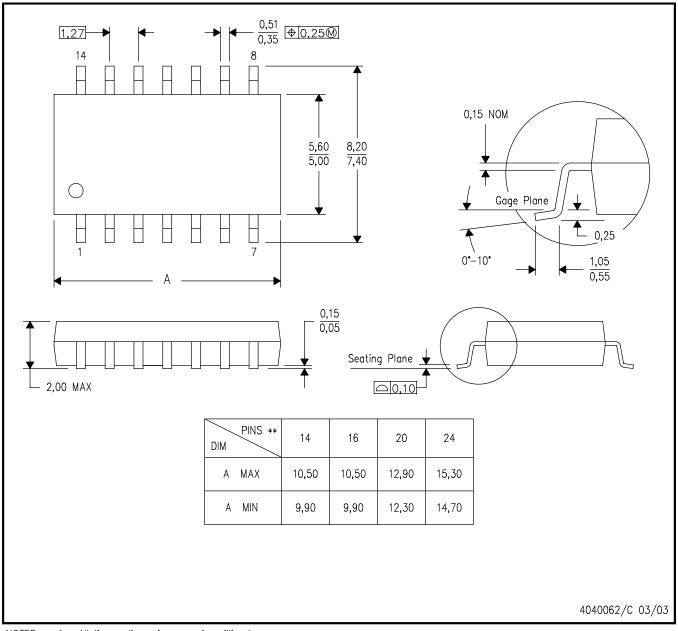


MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE

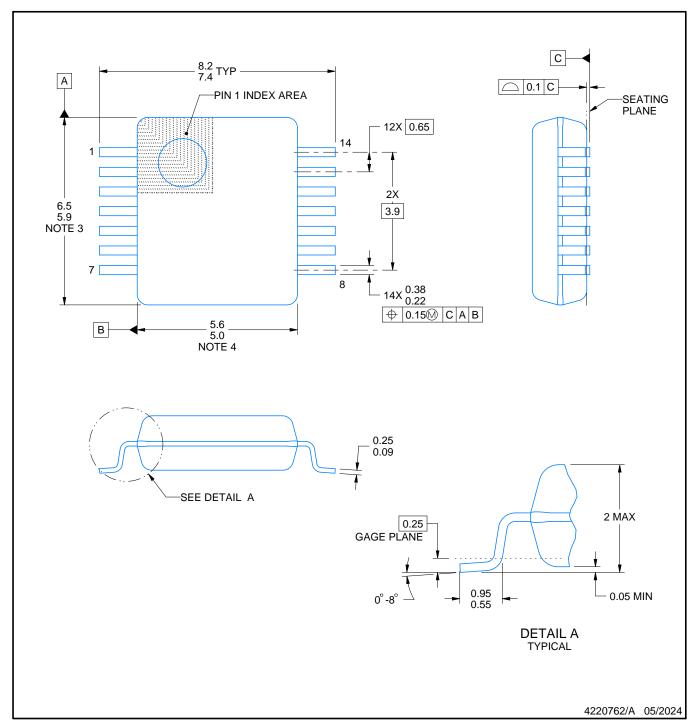


NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.







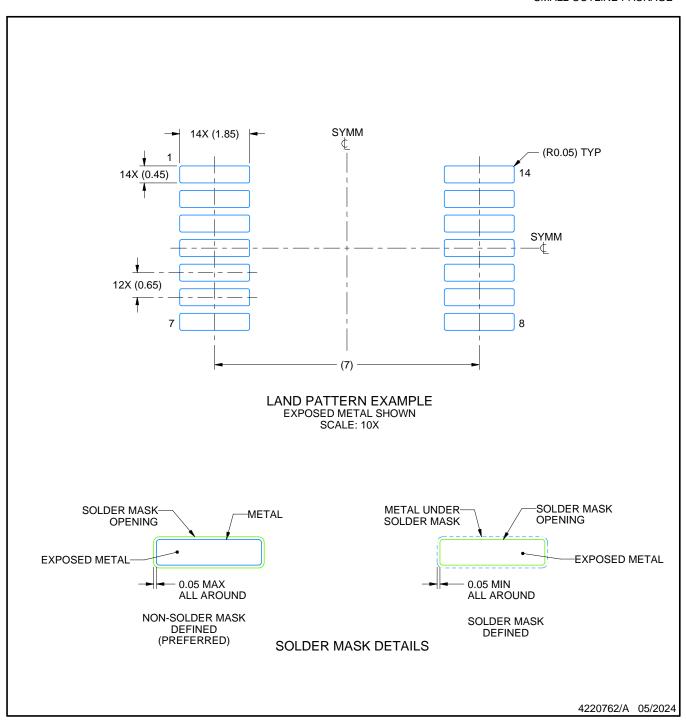
NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
 4. Reference JEDEC registration MO-150.

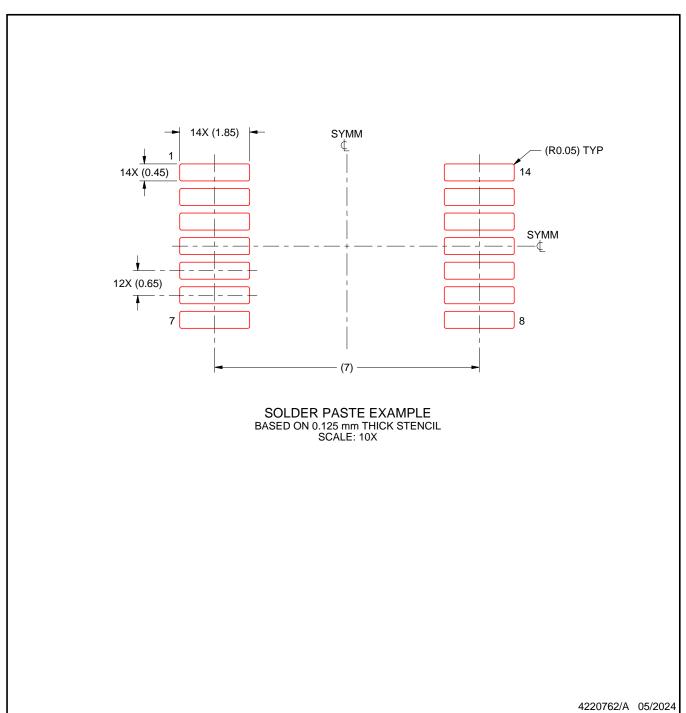




NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



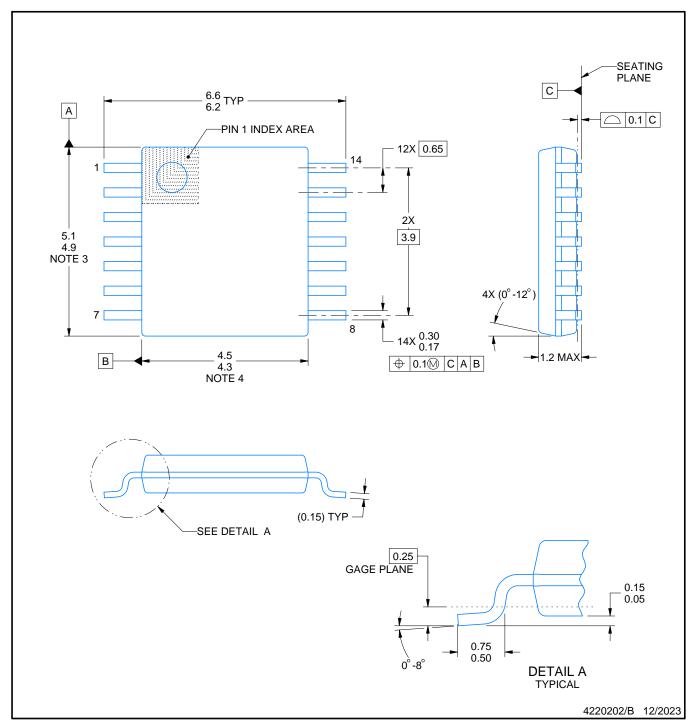


NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.







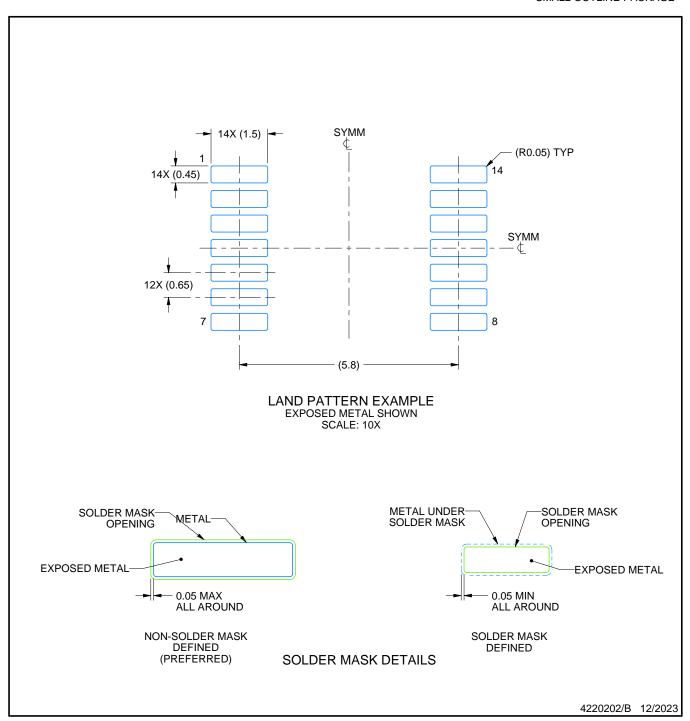
NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



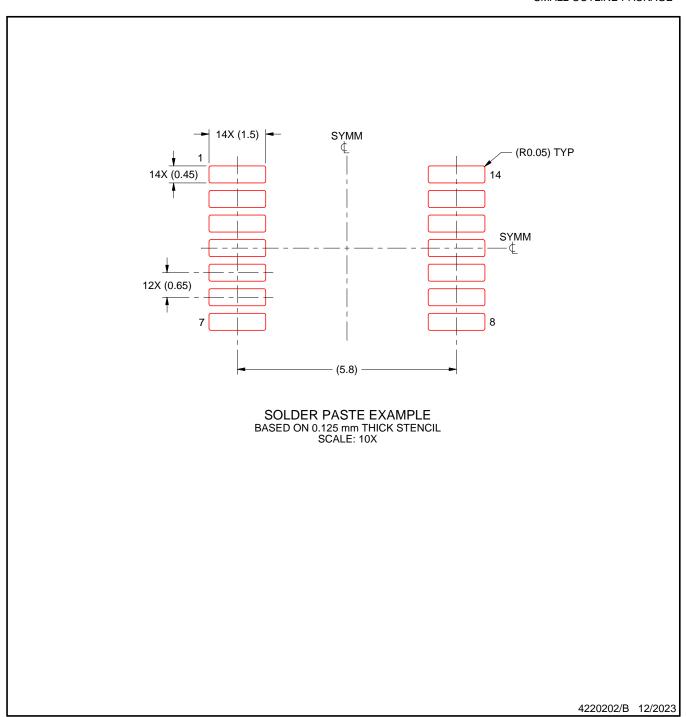


NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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